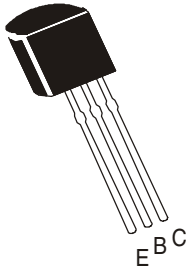


NPN SILICON PLANAR EPITAXIAL TRANSISTOR

BC317/A/B



**TO-92
Plastic Package**

Amplifier Transistor

ABSOLUTE MAXIMUM RATINGS

DESCRIPTION	SYMBOL	VALUE	UNITS
Collector Emitter Voltage	V_{CEO}	45	V
Collector Base Voltage	V_{CBO}	50	V
Emitter Base Voltage	V_{EBO}	6.0	V
Collector Current	I_C	150	mA
Power Dissipation @ $T_a=25^\circ\text{C}$ Derate Above 25°C	P_D	350 2.8	mW mW/ $^\circ\text{C}$
Power Dissipation @ $T_c=25^\circ\text{C}$ Derate Above 25°C	P_D	1.0 8.0	W mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_j, T_{stg}	- 55 to +150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

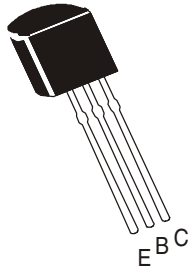
Junction to Case	$R_{th(j-c)}$	125	$^\circ\text{C/W}$
Junction to Ambient in free air	$R_{th(j-a)}$	357	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$ unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
Collector Emitter Voltage	V_{CEO}	$I_C=1\text{mA}, I_B=0$	45			V
Collector Emitter Voltage	V_{CES}	$I_C=100\mu\text{A}, V_{BE}=0$	50			V
Collector Base Voltage	V_{CBO}	$I_C=100\mu\text{A}, I_E=0$	50			V
Emitter Base Voltage	V_{EBO}	$I_E=100\mu\text{A}, I_C=0$	6.0			V
Collector Cut off Current	I_{CBO}	$V_{CB}=20\text{V}, I_E = 0$			30	nA
Emitter Cut off Current	I_{EBO}	$V_{EB}=4\text{V}, I_C = 0$			15	nA
Base Emitter On Voltage	$V_{BE(on)}$	$I_C=2\text{mA}, V_{CE}=5\text{V}$	0.57		0.72	V
		$I_C=10\text{mA}, V_{CE}=5\text{V}$			0.77	V
Collector Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=100\text{mA}, I_B=5\text{mA}$			0.60	V
Base Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=10\text{mA}, I_B=0.5\text{mA}$		0.70		V
		$I_C=100\text{mA}, I_B=5\text{mA}$		0.85		V
DC Current Gain	h_{FE}	$I_C=10\mu\text{A}, V_{CE}=5\text{V}$		90		
			BC317A		40	
		BC317B				
		$I_C=2\text{mA}, V_{CE}=5\text{V}$	BC317	110		450
BC317A	110			220		
BC317B	200			450		

NPN SILICON PLANAR EPITAXIAL TRANSISTOR

BC317/A/B



**TO-92
Plastic Package**

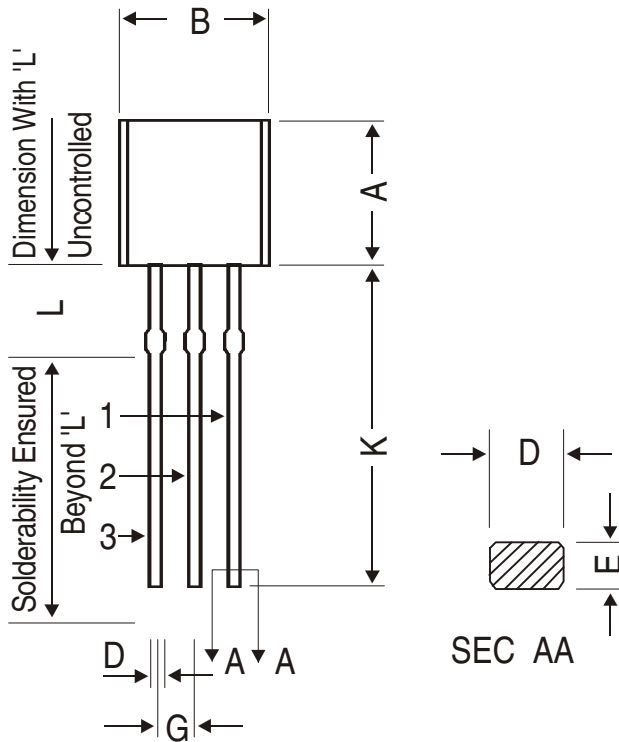
ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$ unless specified otherwise)

DYNAMIC CHARACTERISTICS

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
Noise Figure	NF	$I_C=200\mu\text{A}$, $V_{CE}=5\text{V}$, $R_S=2\text{k}\Omega$, $f=1\text{KHz}$, $BW=200\text{Hz}$			6	dB
Output Capacitance	C_{ob}	$V_{CB}=10\text{V}$, $I_E=0$, $f=1\text{MHz}$			4	pF
Input Capacitance	C_{ib}	$V_{EB}=0.5\text{V}$, $I_C=0$, $f=1\text{MHz}$		11.5		pF
Transition Frequency	f_T	$I_C=10\text{mA}$, $V_{CE}=5\text{V}$		280		MHz
Voltage Feedback Ratio	h_{re}	$I_C=2\text{mA}$, $V_{CE}=5\text{V}$, $f=1\text{KHz}$		2		$\times 10^{-4}$
Input Impedance	h_{ie}	$I_C=2\text{mA}$, $V_{CE}=5\text{V}$, $f=1\text{KHz}$		5		$\text{k}\Omega$
Output Admittance	h_{oe}	$I_C=2\text{mA}$, $V_{CE}=5\text{V}$, $f=1\text{KHz}$		20		μmhos
Small Signal Current Gain	h_{fe}	$I_C=2\text{mA}$, $V_{CE}=5\text{V}$, $f=1\text{KHz}$	BC317	125		500
			BC317A	125		260
			BC317B	240		500

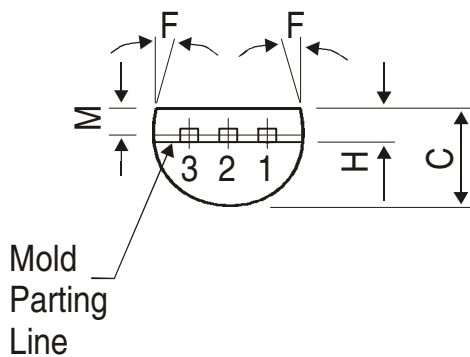
BC317_A_B_Rev220103E

TO-92 Plastic Package



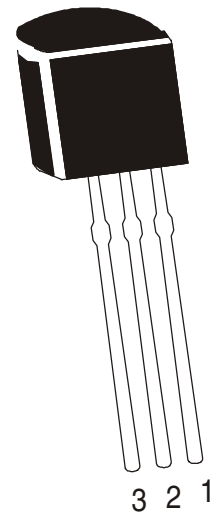
DIM	MIN.	MAX.
A	4.32	5.33
B	4.45	5.20
C	3.18	4.19
D	0.41	0.55
E	0.35	0.50
F	5 DEG	
G	1.14	1.40
H	1.20	1.40
K	12.70	—
L	1.982	2.082
M	1.03	1.20

All dimensions are in mm



PIN CONFIGURATION

1. COLLECTOR
2. BASE
3. EMITTER



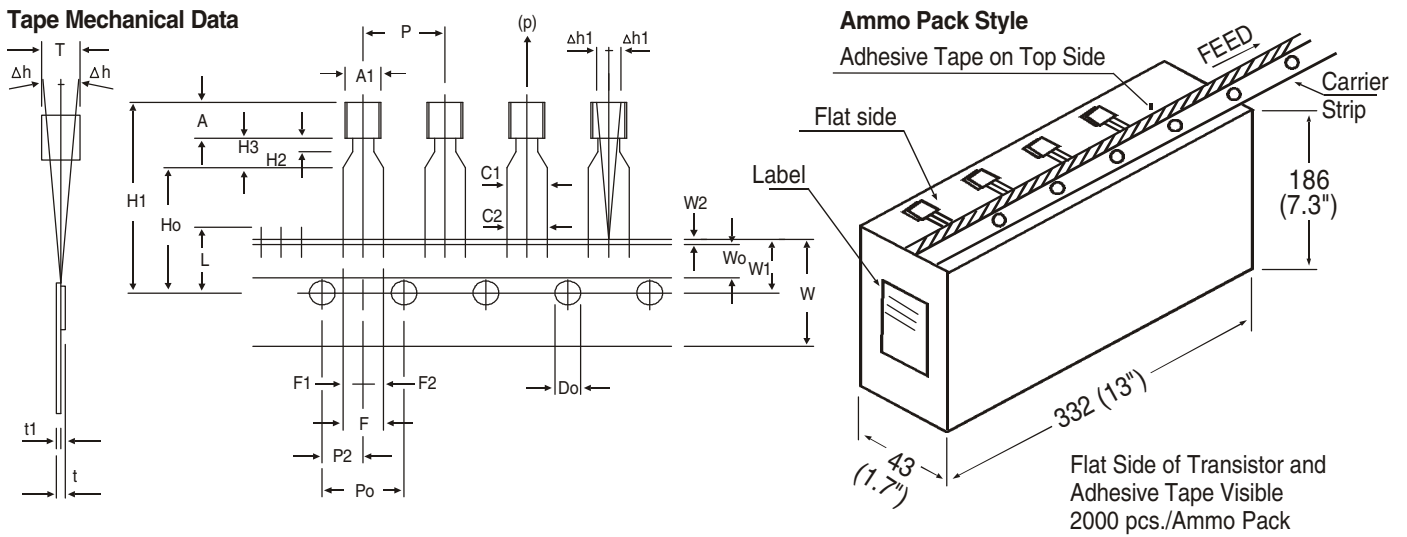
The TO-92 Package, Tape and Ammo Pack Drawings are correct as on the date of issue/revision of this Data Sheet.

The currently valid dimensions and information, may please be confirmed from the TO-92 Drawing in the Packages and Packing Section of the Product Catalogue.

Packing Details

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-92 Bulk	1K/polybag	200 gm/1K pcs	3" x 7.5" x 7.5"	5K	17" x 15" x 13.5"	80K	23 kgs
TO-92 T&A	2K/ammo box	645 gm/2K pcs	12.5" x 8" x 1.8"	2K	17" x 15" x 13.5"	32K	12.5 kgs

TO-92 Tape and Ammo Pack



All dimensions are in mm

ITEM	SYMBOL	SPECIFICATION			
		MIN.	NOM.	MAX.	TOL .
BODY WIDTH	A1	4.0		4.8	
BODY HEIGHT	A	4.8		5.2	
BODY THICKNESS	T	3.9		4.2	
PITCH OF COMPONENT	P		12.7		± 1.0
*1 FEED HOLE PITCH	Po		12.7		± 0.3
*2 FEED HOLE CENTRE TO COMPONENT CENTRE	P2		6.35		± 0.4
DISTANCE BETWEEN OUTER LEADS	F		5.08		+ 0.6 - 0.2
*3 COMPONENT ALIGNMENT SIDE VIEW	Δh		0	1.0	
*4 COMPONENT ALIGNMENT FRONT VIEW	Δh1		0	1.3	
TAPE WIDTH	W		18		± 0.5
HOLD-DOWN TAPE WIDTH	Wo		6		± 0.2
HOLE POSITION	W1		9		+ 0.7 - 0.5
HOLD-DOWN TAPE POSITION	W2		0.5		± 0.2
LEAD WIRE CLINCH HEIGHT	Ho		16		± 0.5
COMPONENT HEIGHT	H1			23.25	
LENGTH OF SNIPPED LEADS	L			11.0	
FEED HOLE DIAMETER	Do		4		± 0.2
*5 TOTAL TAPE THICKNESS	t			1.2	
LEAD - TO - LEAD DISTANCE	F1, F2		2.54		+ 0.4 - 0.1
STAND OFF	H2	0.45		1.45	
CLINCH HEIGHT	H3			3.0	
LEAD PARALLELISM	C1 - C2			0.22	
PULL - OUT FORCE	(p)	6N			

NOTES

1. Maximum alignment deviation between leads will not to be greater than 0.2mm.
2. Maximum non-cumulative variation between tape feed holes shall not exceed 1 mm in 20 pitches.
3. Holddown tape will not exceed beyond the edge(s) of carrier tape and there shall be no exposure of adhesive.
4. There will be no more than three (3) consecutive missing components in a tape.
5. A tape trailer, having at least three feed holes are provided after the last component in a tape.
6. Splices should not interfere with the sprocket feed holes.

REMARKS

- *1 Cumulative pitch error 1.0 mm/20 pitch
- *2 To be measured at bottom of clinch
- *3 At top of body
- *4 At top of body
- *5 t1 0.3 – 0.6 mm

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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